



## Ultrahigh-Speed Switching Applications

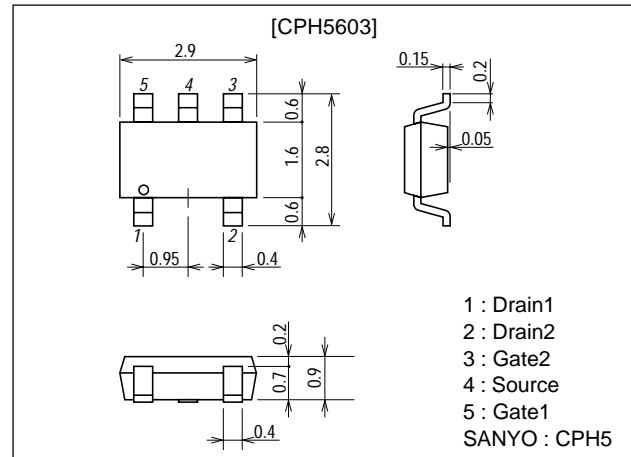
### Features

- Low ON resistance.
- Ultrahigh-speed switching.
- 4V drive.
- Composite type with 2 MOSFETs contained in a single package, facilitating high-density mounting.

### Package Dimensions

unit:mm

2168



### Specifications

#### Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	$V_{DSS}$		-30	V
Gate-to-Source Voltage	$V_{GSS}$		$\pm 20$	V
Drain Current (DC)	$I_D$		-1.0	A
Drain Current (pulse)	$I_{DP}$	$PW \leq 10\mu s$ , duty cycle $\leq 1\%$	-4.0	A
Allowable Power Dissipation	$P_D$	Mounted on a ceramic board (600mm $\times$ 0.8mm) 1unit	0.9	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C

#### Electrical Characteristics at Ta = 25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Drain-to-Source Breakdown Voltage	$V_{(BR)DSS}$	$I_D = -1mA$ , $V_{GS} = 0$	-30			V
Zero-Gate Voltage Drain Current	$I_{DSS}$	$V_{DS} = -30V$ , $V_{GS} = 0$			-10	$\mu A$
Gate-to-Source Leakage Current	$I_{GSS}$	$V_{GS} = \pm 16V$ , $V_{DS} = 0$			$\pm 10$	$\mu A$
Cutoff Voltage	$V_{GS(off)}$	$V_{DS} = -10V$ , $I_D = -1mA$	-1.0		-2.5	V
Forward Transfer Admittance	$ y_{fs} $	$V_{DS} = -10V$ , $I_D = -500mA$	0.6	0.9		S
Static Drain-to-Source On-State Resistance	$R_{DS(on)1}$	$I_D = -500mA$ , $V_{GS} = -10V$		360	470	$m\Omega$
	$R_{DS(on)2}$	$I_D = -300mA$ , $V_{GS} = -4V$		690	970	$m\Omega$
Input Capacitance	$C_{iss}$	$V_{DS} = -10V$ , $f = 1MHz$		85		pF
Output Capacitance	$C_{oss}$	$V_{DS} = -10V$ , $f = 1MHz$		55		pF
Reverse Transfer Capacitance	$C_{rss}$	$V_{DS} = -10V$ , $f = 1MHz$		13		pF

Marking : FC

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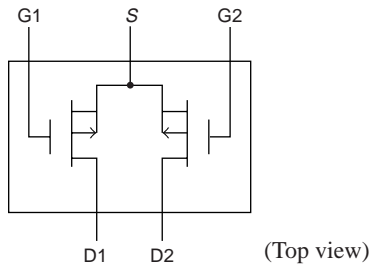
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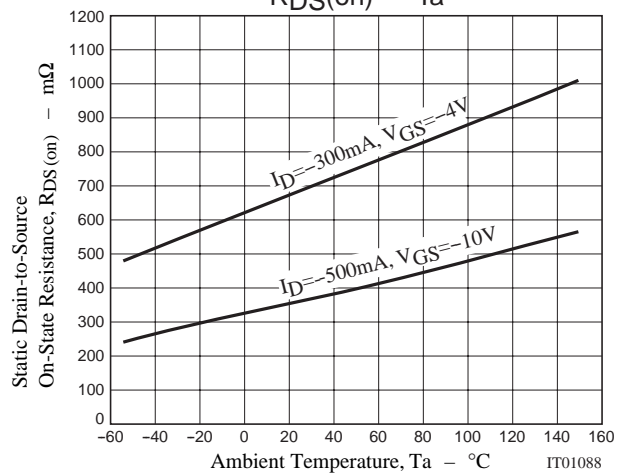
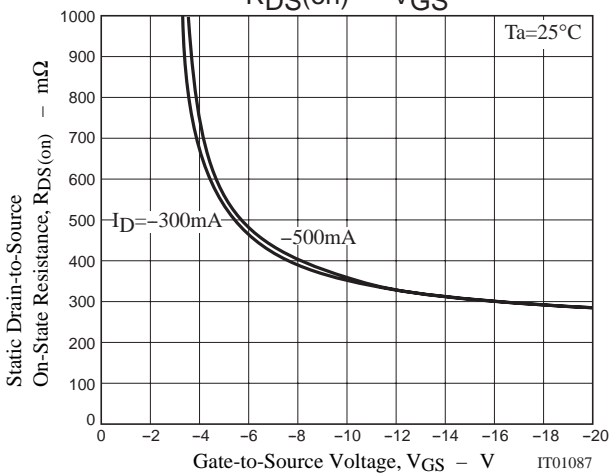
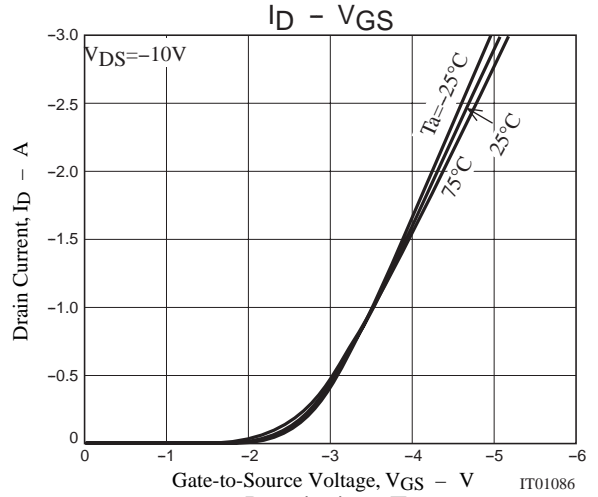
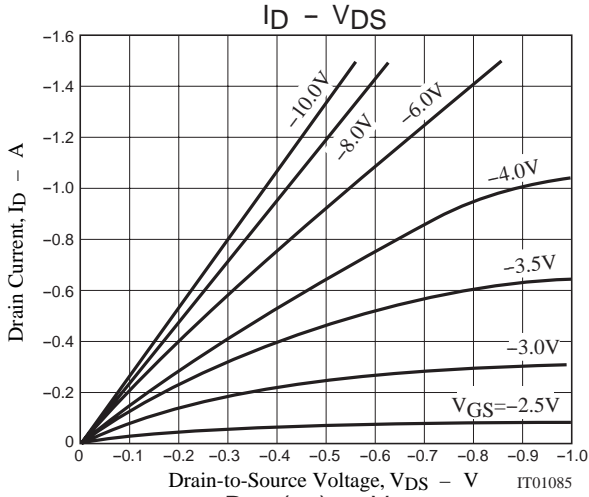
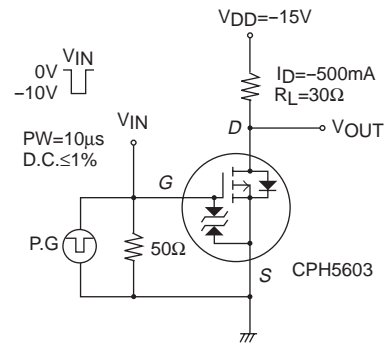
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Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Turn-ON Delay Time	$t_{d(on)}$	See specified Test Circuit		8		ns
Rise Time	$t_r$	See specified Test Circuit		14		ns
Turn-OFF Delay Time	$t_{d(off)}$	See specified Test Circuit		36		ns
Fall Time	$t_f$	See specified Test Circuit		24		ns
Total Gate Charge	$Q_g$	$V_{DS}=-10V, V_{GS}=-10V, I_D=-1.0A$		4		nC
Gate-to-Source Charge	$Q_{gs}$	$V_{DS}=-10V, V_{GS}=-10V, I_D=-1.0A$		1		nC
Gate-to-Drain "Miller" Charge	$Q_{gd}$	$V_{DS}=-10V, V_{GS}=-10V, I_D=-1.0A$		1		nC
Diode Forward Voltage	$V_{SD}$	$I_S=-1.0A, V_{GS}=0$		-0.9	-1.5	V

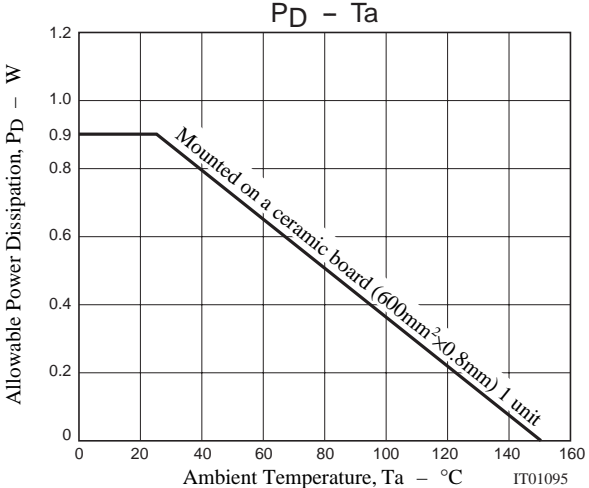
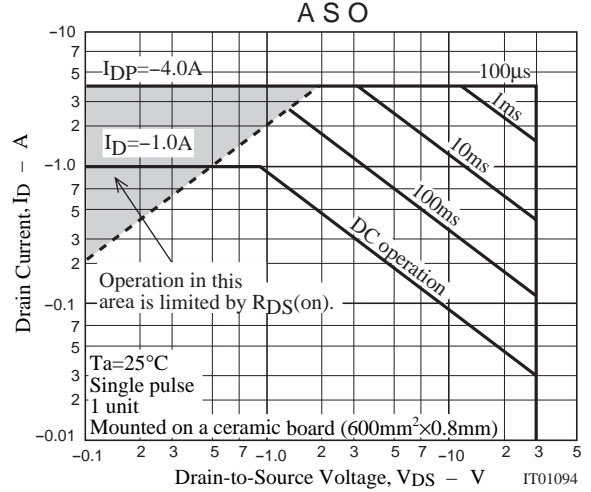
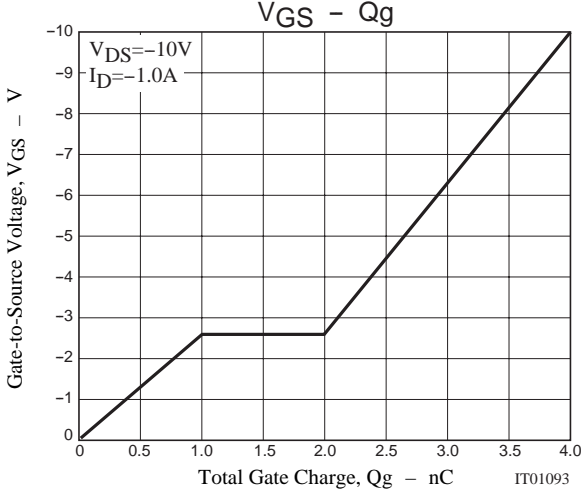
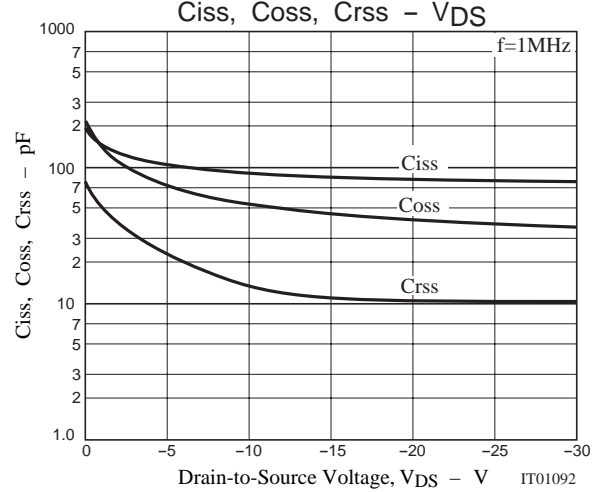
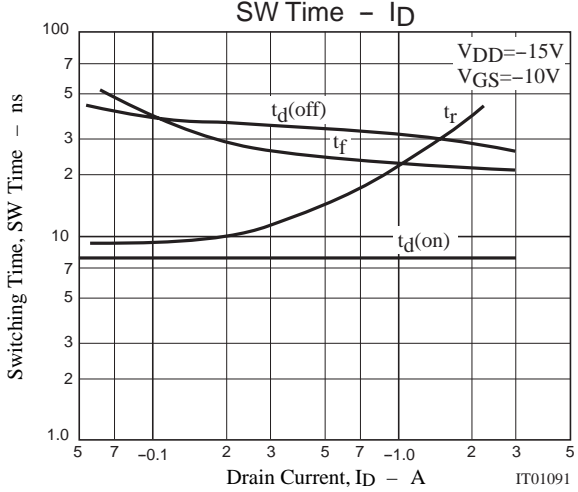
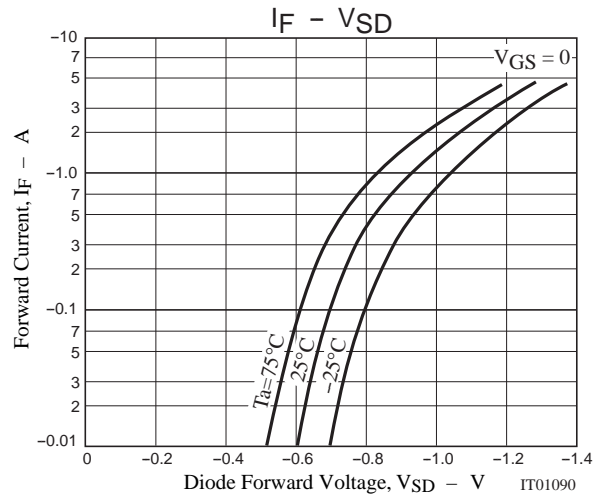
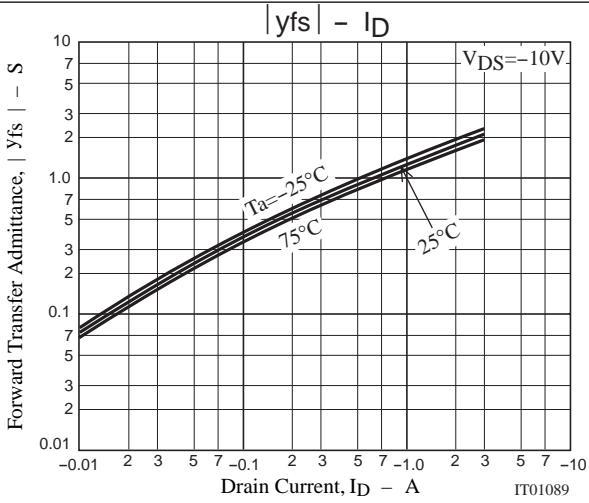
## Electrical Connection



## Switching Time Test Circuit



# CPH5603



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